

37 C.F.R. § 1.323

## U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

Docket Number: 10191/1924 Conf. No.: 6125

Application Number Filing Date Examiner Art Unit 10/017,772 October 29, 2001 Andre J. Allen 2855

Patent Number Issue Date 6,832,523 **December 21, 2004** 

Certificate

Invention Title

MICROMECHANICAL COMPONENT AND MANUFACTURING METHOD

RECUEST FOR CERTIFICATE OF

**CORRECTION PURSUANT TO** 

Inventor(s)

JUL 0 1 2005

Hubert BENZEL et al.

of Correction

Address to:

Commissioner For Patents P. O. Box 1450 Alexandria, VA 22313-1450

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner of Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on:

Applicants hereby request that the enclosed Certificate of Correction be issued for the above Patent under authority of 35 U.S.C. § 255. The exact column and line number where the errors occur in the patent are listed on the enclosed certificate.

The errors that appear in this patent by nature of applicants' mistakes are of a clerical, typographical or minor nature or character and occurred in good faith. Corrections thereof, do not involve changes in the patent as would constitute new matter or would require reexamination.

Please charge payment of the 37 C.F.R. §1.20(a) Certificate of Correction fee of \$100.00, and any additional fee to Deposit Account No. 11-0600.

Dated: 6/22/95

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## UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT No. : 6,832,523 / )

**DATED** : December 21, 2004

INVENTOR(S): Hubert BENZEL et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1, lines 35-36, change "using – and p-doped semiconductors" to --using n- and p-doped semiconductors--

Column 1, lines 41-42, change "by way of – and p-doped semiconductors areas" to -by way of n- and p-doped semiconductors areas--

Column 8, lines 1-2, change "at least one Pelter element" to --at least one Peltier element--

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